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We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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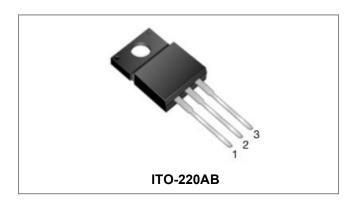




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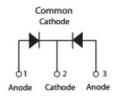
MBRF4080CTL SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V _{RRM} V _{RWM}	-	80	V
DC Blocking Voltage	V _R			-
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=80°C, rectangular wave form	20(Per Leg) 40(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	400	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@20A, Pulse, T _J = 25 °C	-	0.75	V
Reverse Current(Per Leg)*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	-	1.0	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$	-	900	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs
RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, T _A = 25 °C)	V _{ISO}	Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	-	4500	V
,		Clip mounting, the epoxy body is inside the heatsink.	-	3500	
		Screw mounting, the epoxy body is inside the heatsink.	-	1500	

^{*} Pulse width < 300 µs, duty cycle < 2%

[•] China - Germany - Korea - Singapore - United States •

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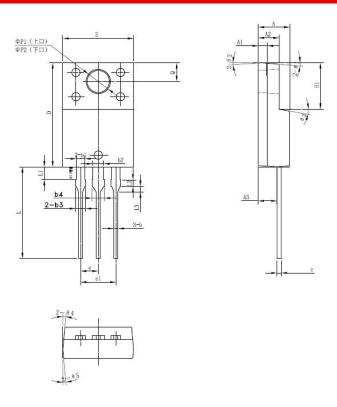




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _θ JC	DC operation	2.3	°C/W
Typical Thermal Resistance, Case to Heat Sink	R _{ecs}	Mounting surface, smooth and greased(only for TO-220)	0.50	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

Mechanical Dimensions ITO-220AB



CVMPOL	Millimeters					
SYMBOL	MIN.	TYP.	MAX.			
Α	4.30	4.50	4.70			
A1	1.10	1.30	1.50			
A2	2.80	3.00	3.20			
A3	2.50	2.70	2.90			
b	0.50	0.60	0.75			
b1	1.10	1.20	1.35			
b2	1.50	1.60	1.75			
b3	1.20	1.30	1.45			
b4	1.60	1.70	1.85			
С	0.50	0.60	0.75			
D	14.80	15.00	15.20			
E	9.96	10.16	10.36			
е		2.55				
e1		5.10				
H1	6.50	6.70	6.90			
L	12.70	13.20	13.70			
L1	1.60	1.80	2.00			
L2	0.80	1.00	1.20			
L3	0.60	0.80	1.00			
ΦΡ1 (上□)	3.30	3.50	3.70			
ΦP2 (下口)	2.99	3.19	3.39			
Q	2.50	2.70	2.90			
Θ1		5°				
Θ2		4°				
Θ3		10°				
Θ4		5°				
Θ5		5°				

Ordering Information

Device	Package	Shipping
MBRF4080CTL	ITO-220AB	50 pcs/ tube
	(Pb-Free)	30 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

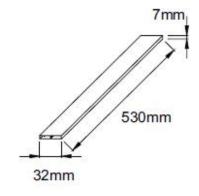
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Tube Specification



Marking Diagram



Where XXXXX is YYWWL

MBR = Device Type
F = Package type
40 = Forward Current (40A)
80 = Reverse Voltage (80V)
CTL = Configuration
SSG = SSG
YY = Year
WW = Week

= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

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